Protection Device

TVS (Transient Voltage Suppressor)

ESD221-U1-02EL

Uni-directional, 5.3 V, 38 pF, 0402, RoHS and Halogen Free compliant

ESD221-U1-02EL

Data Sheet

Revision 1.0, 2014-05-20
Final

Power Management & Multimarket

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Edition 2014-05-20

Published by
Infineon Technologies AG
81726 Munich, Germany

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1 Product Overview

1.1 Features

- ESD / transient protection of data and V_{BUS} lines according to:
  - **IEC61000-4-2 (ESD): ±25 kV (air) ±20 kV (contact)**
  - **IEC61000-4-4 (EFT): ±2.5 kV / ±50 A (5/50 ns)**
  - **IEC61000-4-5 (Surge): ±5.5 A (8/20 µs)**
- Uni-directional, working voltage up to V_{RWM} **= ±5.3 V**
- Medium capacitance: C_L **= 38 pF (typical)**
- Very low clamping voltage V_{CL} **= +10 / -5 V (typical) at** I_{TLP} **= 16 A**
- Low reverse current I_R **< 100 nA at** V_R **= 3.3 V**
- Pb-free (RoHS compliant) and halogen free package

1.2 Application Examples

- V_{BUS} line protection in USB ports
- Keypad, touchpad, buttons, convenience keys
- LCD displays, Camera, audio lines, mobile communication, Consumer products (E-Book, MP3, DVD, DSC...)
- Notebooks tablets and desktop computers and their peripherals

1.3 Product Description

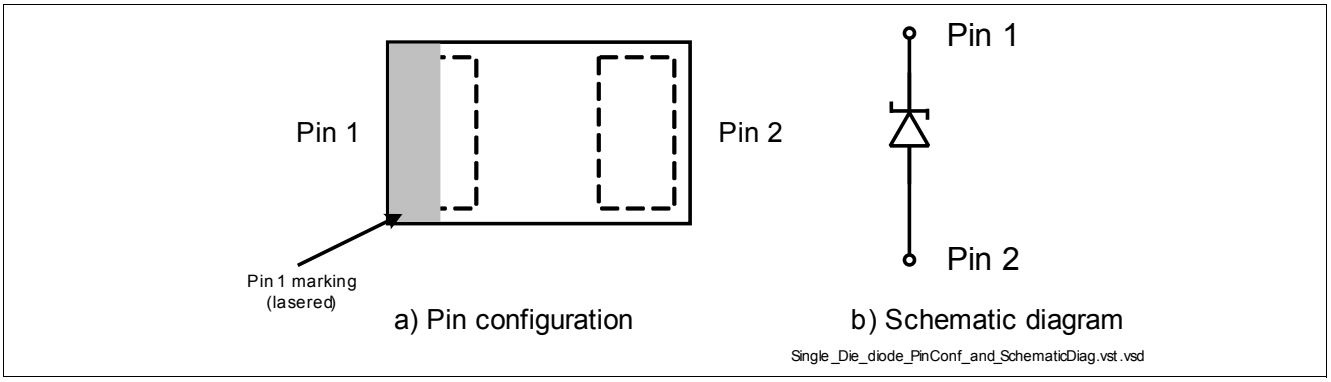

Figure 1-1 Pin Configuration and Schematic Diagram

Table 1-1 Part Information

Type	Package	Configuration	Marking code
ESD221-U1-02EL	TSLP-2-19	1 line,uni-directional	E

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2 Maximum Ratings

Table 2-1 Maximum Ratings at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values	Unit
ESD air discharge[1)] ESD contact discharge[1)]	V_{ESD}	±25 ±20	kV
Peak pulse power[2)]	P_{PK}	60	W
Peak pulse current[2)]	I_{PP}	±5.5	A
Operating temperature range	T_{OP}	-55 to 125	°C
Storage temperature	T_{stg}	-65 to 150	°C

1) V_{ESD} according to IEC61000-4-2

2) Non-repetitive current pulse 8/20µs exponential decay waveform according to IEC61000-4-5

Attention: Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

3 Electrical Characteristics at T_A = 25 °C, unless otherwise specified

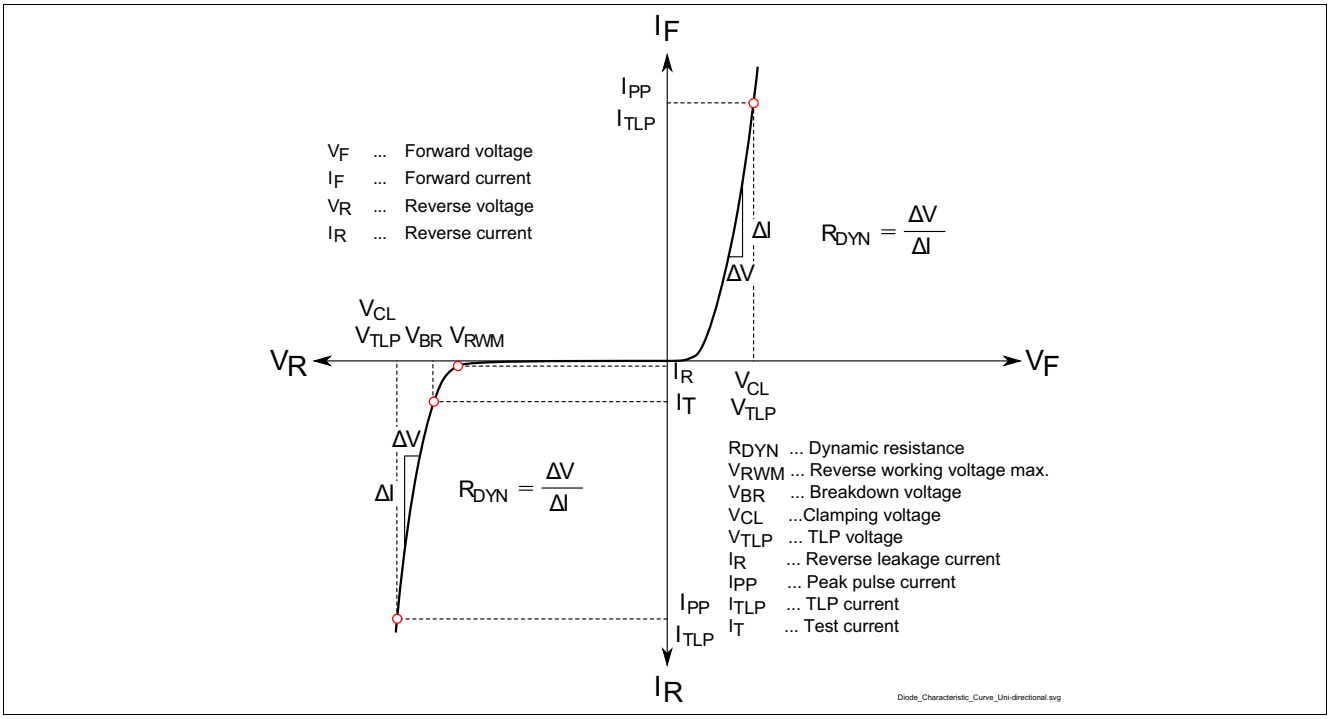

Figure 3-1 Definitions of electrical characteristics

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Table 3-1 DC Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Reverse working voltage	V_{RWM}	–	–	5.3	V	from Pin 1 to Pin 2
Breakdown voltage	V_{BR}	5.7	6.4	7.5	V	I_T = 1 mA
Reverse current	I_R	–	–	100	nA	V_R = 3.3 V

Table 3-2 AC Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Line capacitance	C_L	–	38	–	pF	V_R = 0 V, f = 1 MHz
		–	20	–		V_R = 2.5 V, f = 1 MHz
Series inductance	L_S	–	0.4	–	nH	

Table 3-3 ESD and Surge Characteristics at T_A = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clamping voltage[1)]	V_{CL}	–	10	–	V	I_{TLP} = 16 A, t_p = 100 ns, Pin 1 to Pin 2
		–	14	–		I_{TLP} = 30 A, t_p = 100 ns, Pin 1 to Pin 2
		–	5	–		I_{TLP} = 16 A, t_p = 100 ns, Pin 2 to Pin 1
		–	7	–		I_{TLP} = 30 A, t_p = 100 ns, Pin 2 to Pin 1
Clamping voltage[2)]		–	7	9		I_{PP} = 1 A, t_p = 8/20 µs, Pin 1 to Pin 2
		–	8	10		I_{PP} = 3.5 A, t_p = 8/20 µs, Pin 1 to Pin 2
		–	9	11		I_{PP} = 5.5 A, t_p = 8/20 µs, Pin 1 to Pin 2
		–	1.2	2		I_{PP} = 1 A, t_p = 8/20 µs, Pin 2 to Pin 1
		–	2	3		I_{PP} = 3.5 A, t_p = 8/20 µs, Pin 2 to Pin 1
		–	2.5	3.5		I_{PP} = 5.5 A, t_p = 8/20 µs, Pin 2 to Pin 1
Dynamic resistance[1)]	R_{DYN}	–	0.3	–	Ω	t_p = 100 ns

1) Please refer to Application Note AN210[1] TLP parameter: Z_0 = 50 Ω , t_p = 100ns, t_r = 300ps.

2) Non-repetitive current pulse 8/20µs exponential decay waveform according to IEC61000-4-5

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4 Typical Characteristics Diagrams

Typical characteristics diagrams at T_A = 25°C, unless otherwise specified

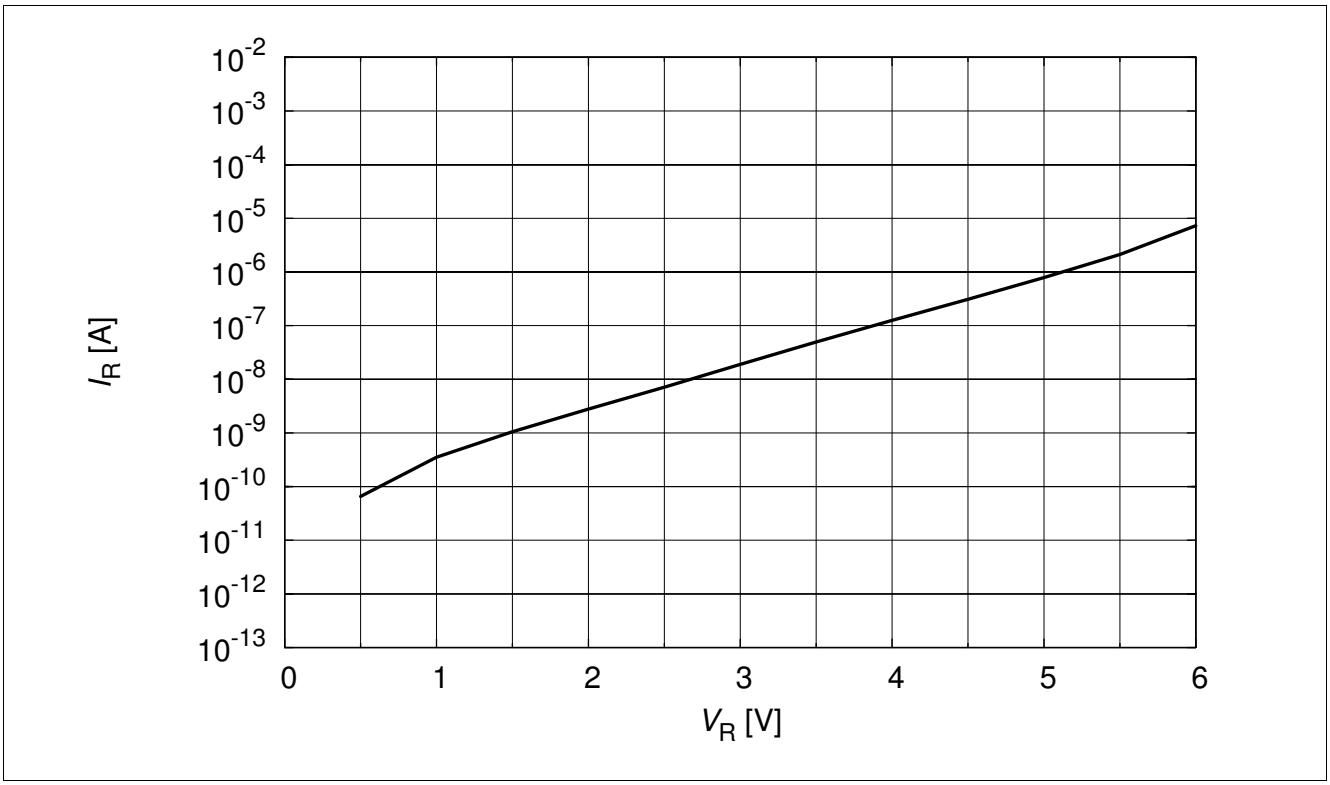

Figure 4-1 Reverse leakage current: $I_R = f(V_R)$

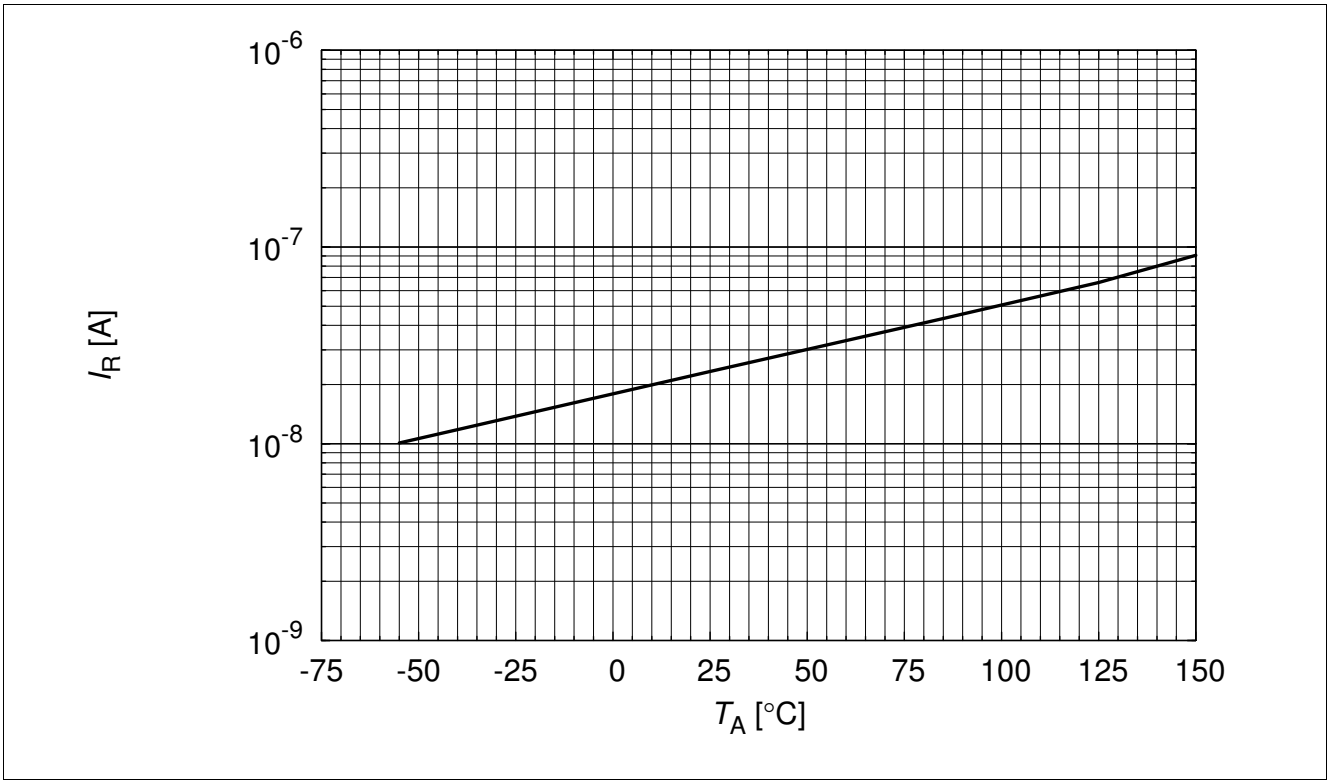

Figure 4-2 Reverse leakage current: $I_R = f(T_A)$, V_R = 3.3 V

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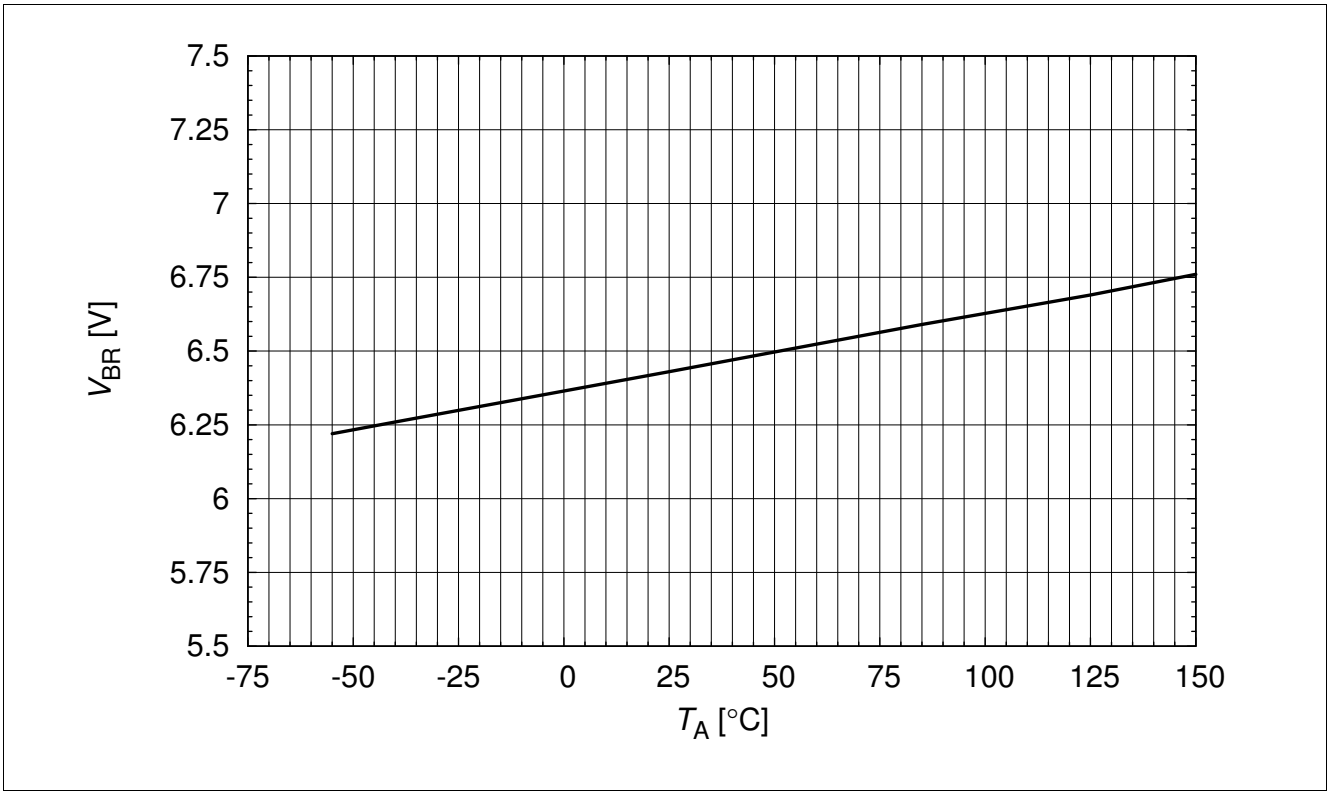

Figure 4-3 Breakdown voltage: $V_{BR} = f(T_A)$, I_R = 1 mA

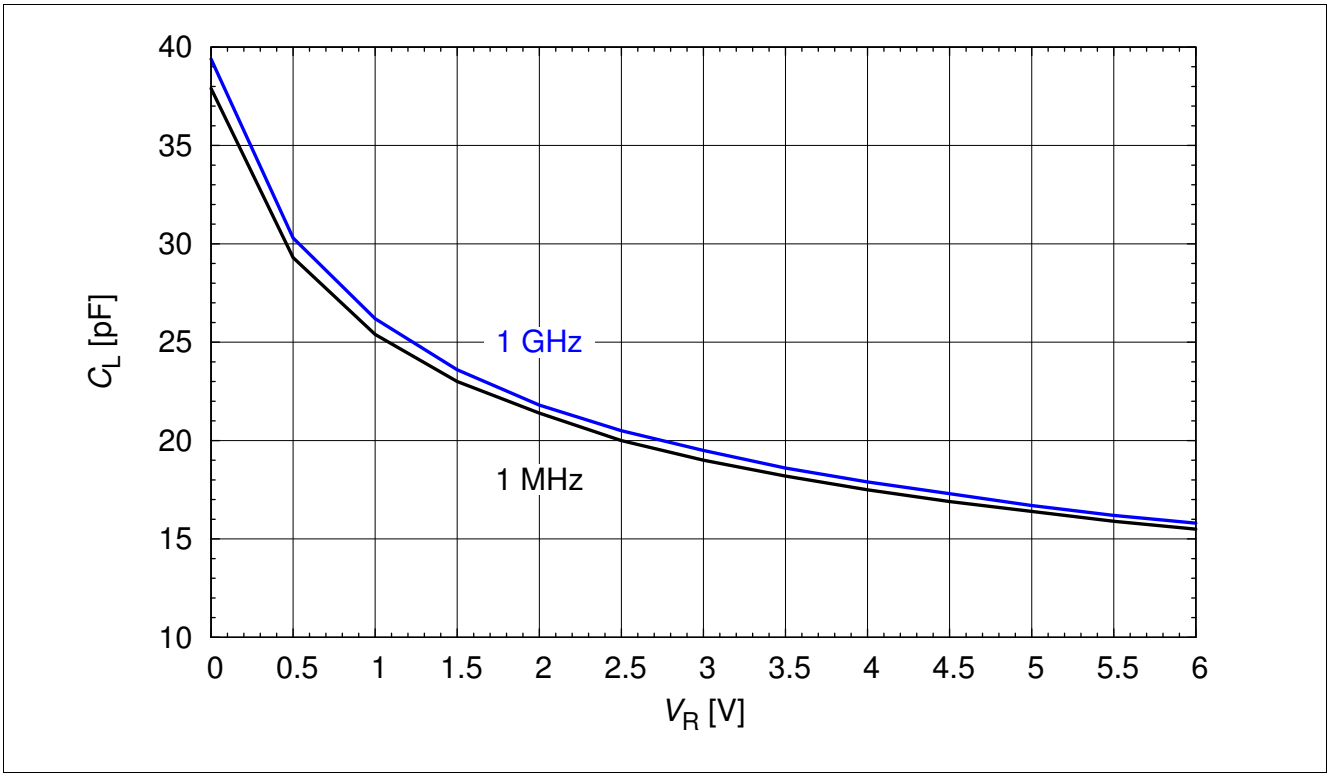

Figure 4-4 Line capacitance: $C_L = f(V_R)$

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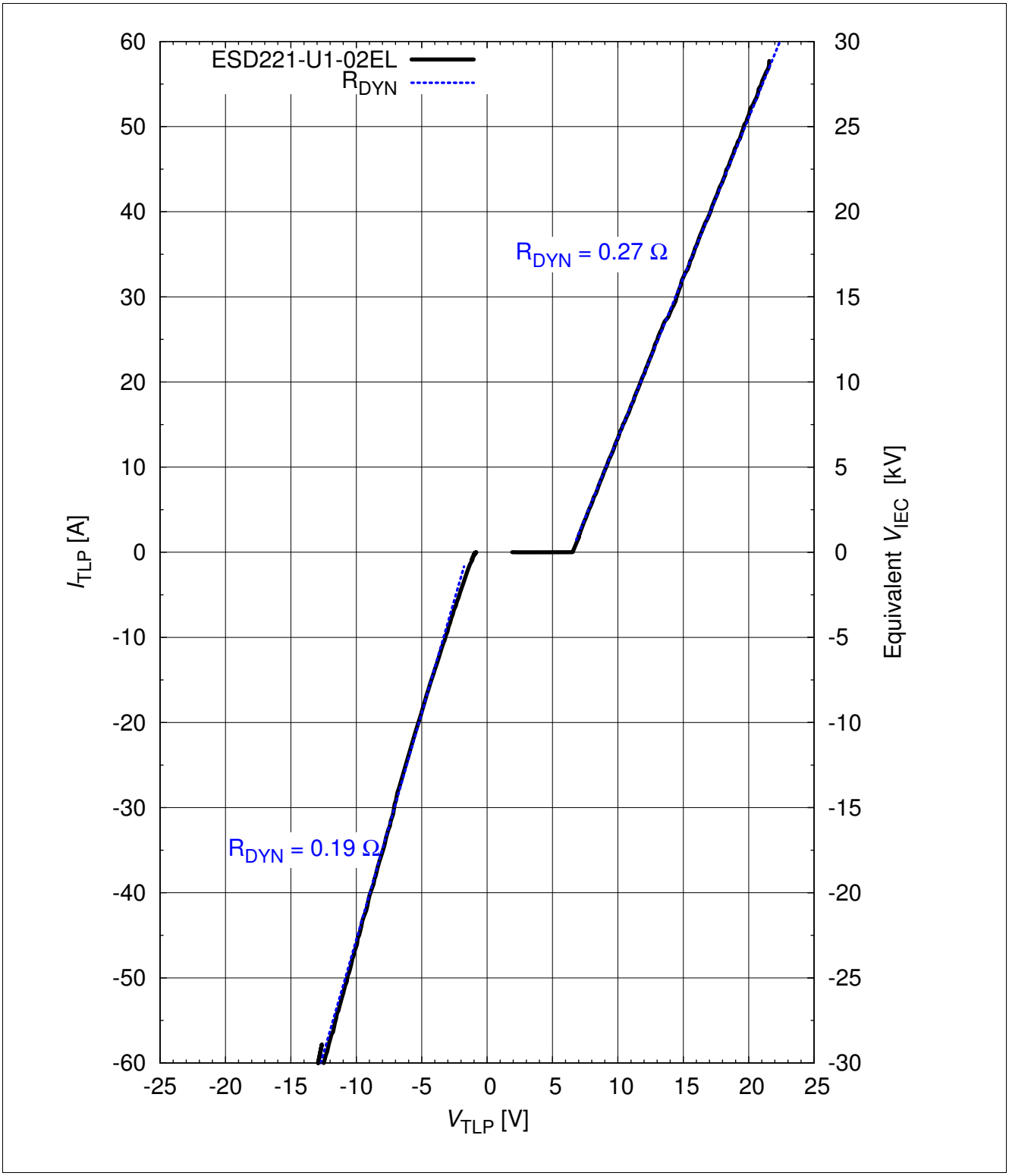

Figure 4-5 Clamping voltage (TLP): $I_{TLP} = f(V_{TLP})$ [1], pin 1 to pin 2

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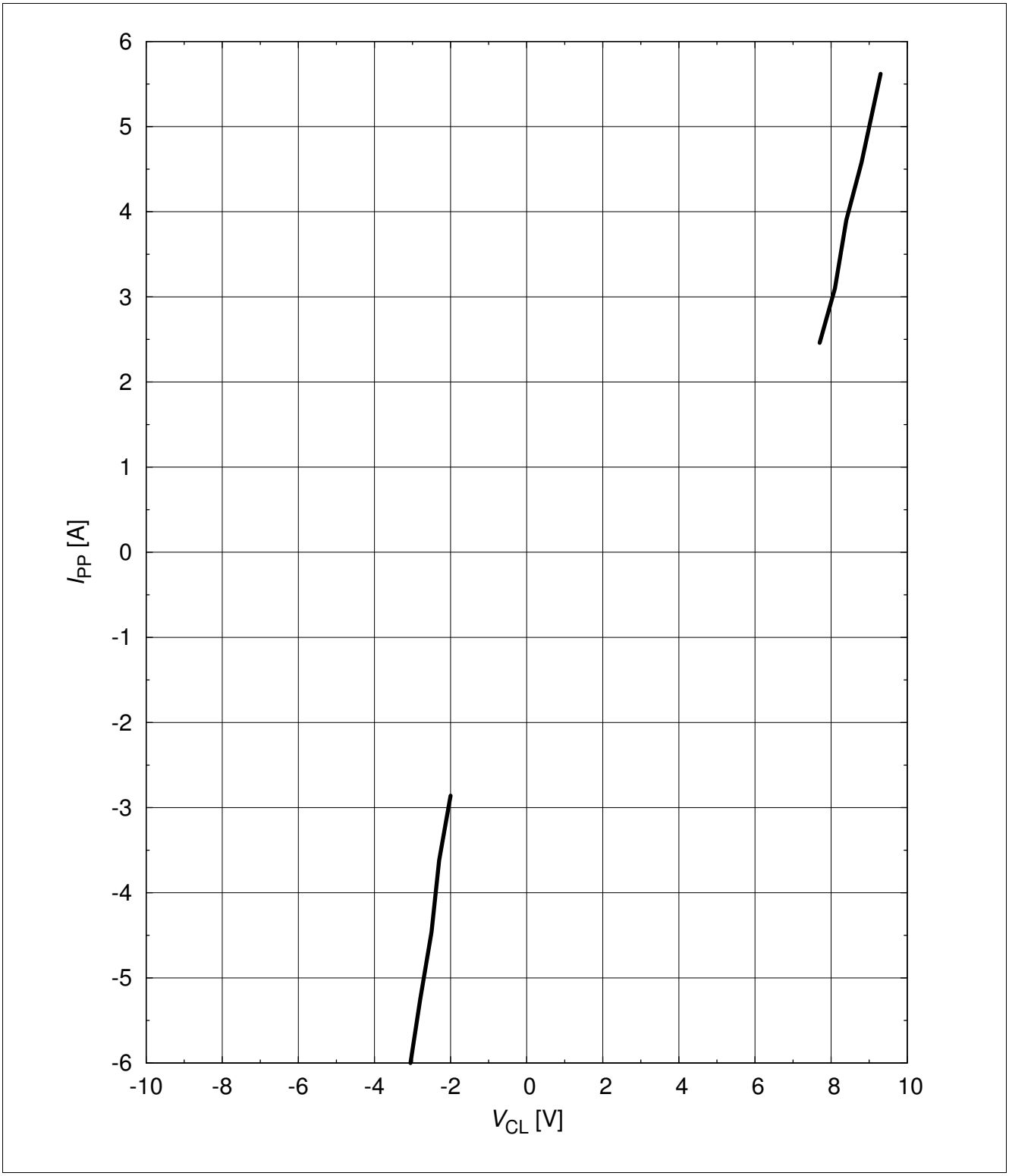

Figure 4-6 Clamping voltage (Surge): $I_{PP} = f(V_{CL})$ [1], pin 1 to pin 2

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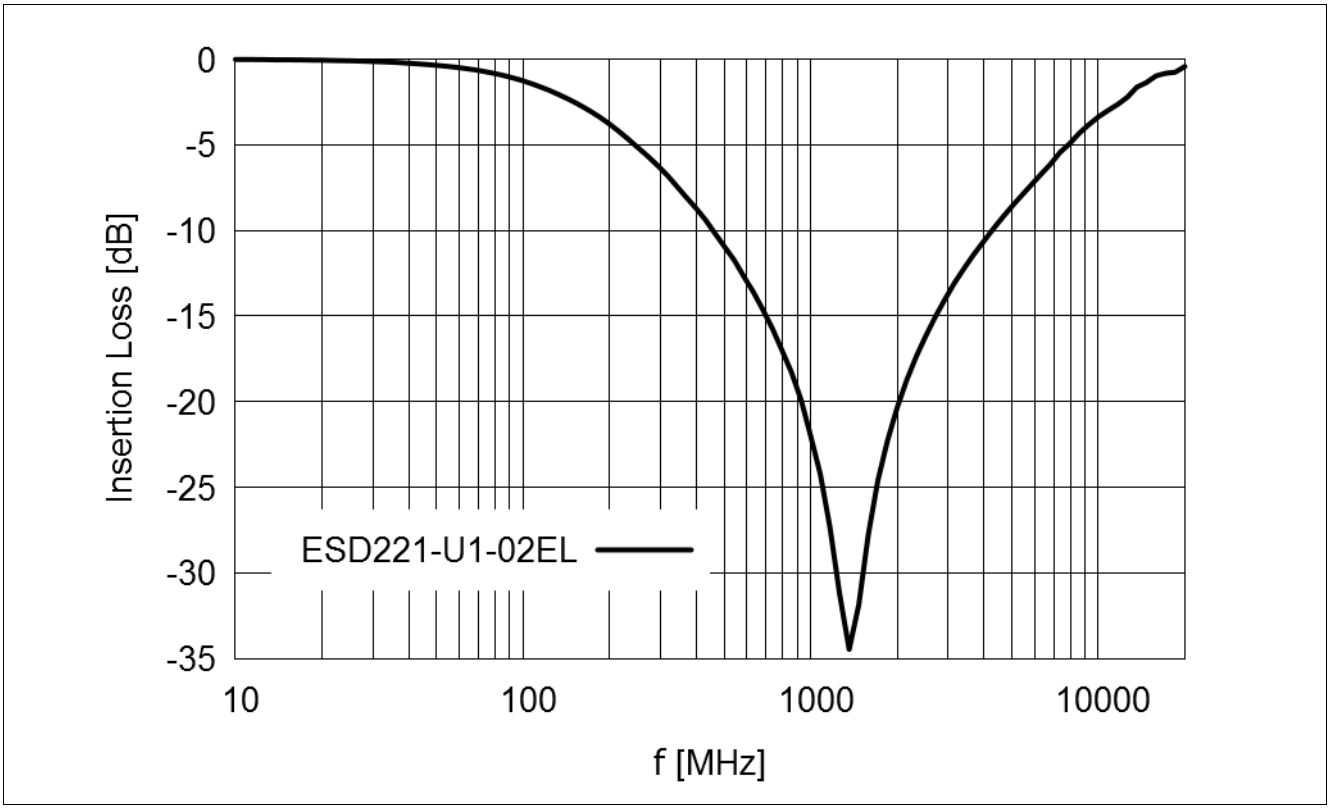

Figure 4-7 Insertion loss vs. frequency in a 50 Ω system

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5 Package Information

5.1 TSLP-2-19

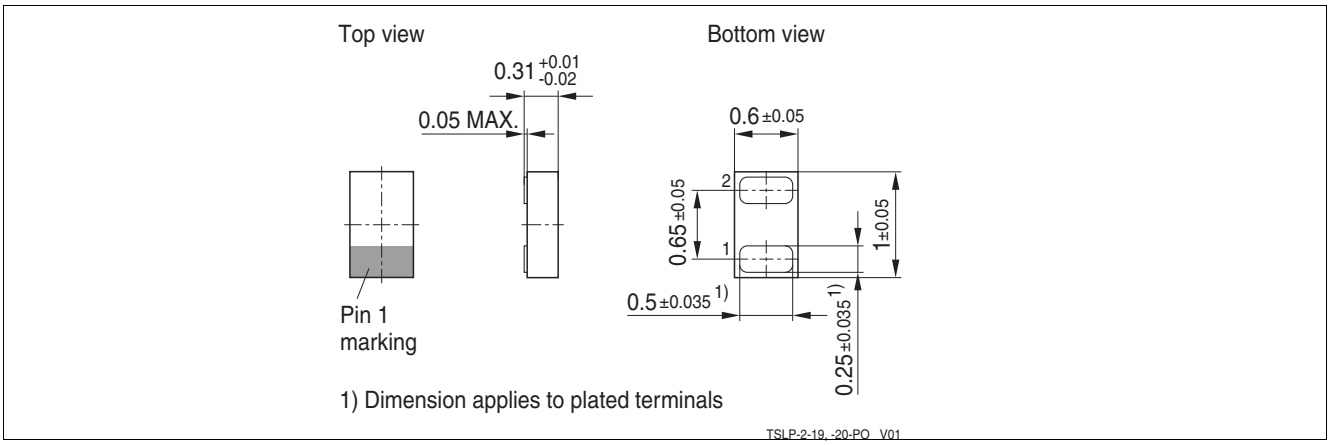

Figure 5-1 TSLP-2-19: Package outline

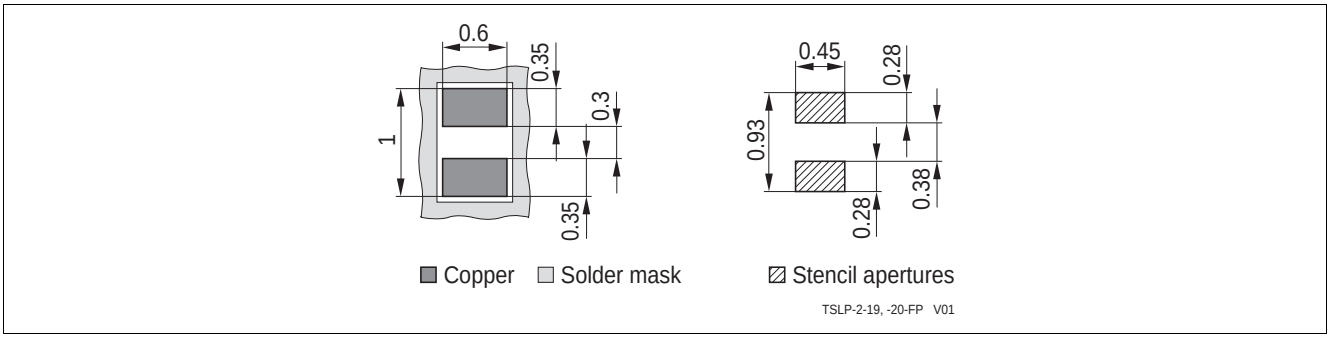

Figure 5-2 TSLP-2-19: Footprint

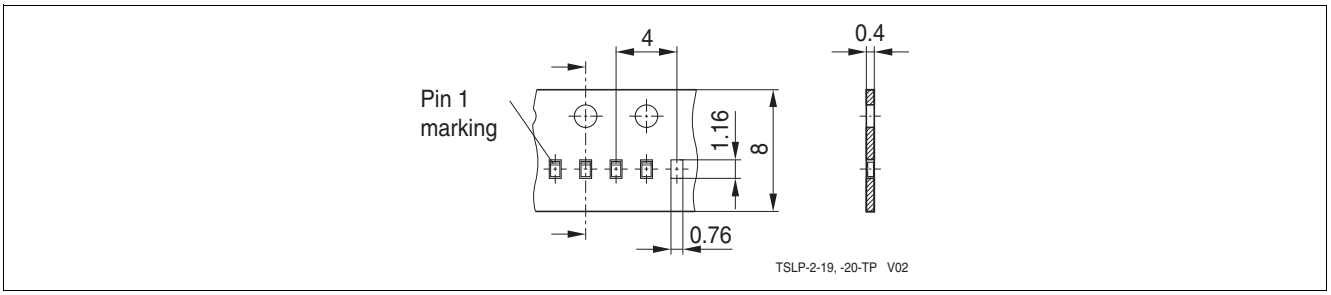

Figure 5-3 TSLP-2-19: Packing

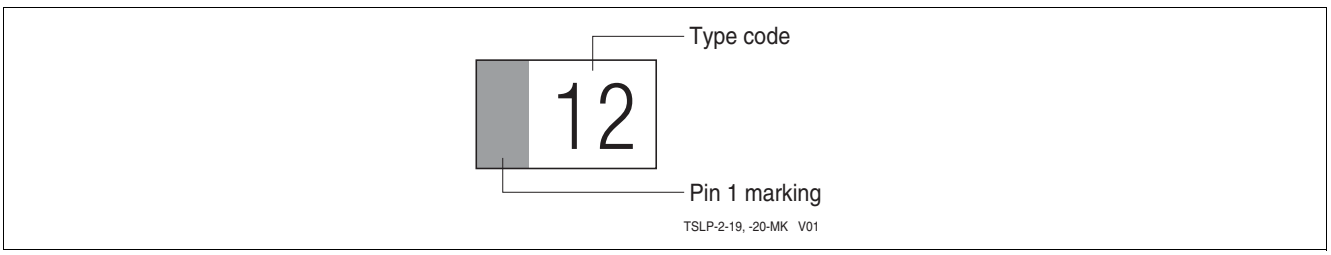

Figure 5-4 TSLP-2-19: Marking example, Type code see: Table 1-1 “Part Information” on Page 3

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References

[1] Infineon AG - **Application Note AN210:** Effective ESD Protection design at System Level Using VF-TLP Characterization Methodology

[2] Infineon AG - Recommendations for PCB Assembly of Infineon TSLP and TSSLP Packages

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Revision History	
Page or Item	**Subjects (major changes since previous revision)**
Revision 1.0, 2014-05-20	
5	Update of Table 2-2)

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